Lumics





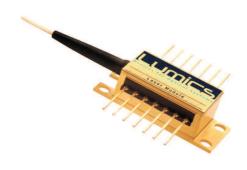








LU0786M250 786nm Single Mode Laser Module up to 250mW c.w. Operating Power



Description:

The Lumics LU0786M250 laser diode module contains an optimized GaAs substrate based quantum well high power laser diode. It has been designed for customer specific applications and is available with special FBG's and fibers. The extremely stringent reliability requirements are achieved through our patent pending innovative technology. This includes careful design, exactly defined manufacturing and extensive testing. The qualification contains a set of optoelectronic, thermal and mechanical tests. Each laser diode module is individually serialized for traceability and is shipped with a specified set of test data.

Features & Functions:

- Wavelength 786nm
- Up to 250mW c.w. operating power
- Up to 550mW peak power
- Rise time < 2nsec
- internal TEC temperaure stabilisation

Options:

- FBG-options
- PM-fiber option

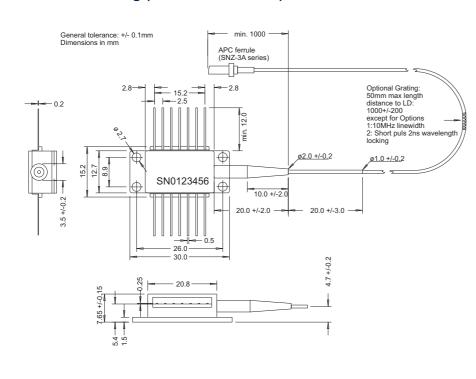
Benefits:

- All laser welded
- Field proven reliability
- Hermetic sealing
- Telcordia compliant package
- RoHS compliant

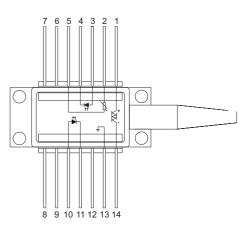
Applications:

- Analytical instruments
- Sensor applications
- Pumping
- Printing

Module Drawing (dimensions in mm)



Pin Connections



Pin			
1	Cooler (+)	8	nc
2	Thermistor	9	nc
3	PD Anode (+)	10	LD Anode (+)
4	PD Cathode (-)	11	LD Cathode (-)
5	Thermistor	12	nc
6	nc	13	Case ground
7	nc	14	Cooler (-)

We manufacture diode lasers.



Typical Electrical and Optical Characteristics (at 25°C (T_{chip} and T_{case}) and Begin of Life (BOL)):

	Conditions						
Operating power	C.W.	P_{op}		250		mW	
Operating current	C.W.	lop		390	450	mA	
Pulsed operating peak power	< 500ns / duty cycle <5%	Pop		550		mW	
Pulsed operating peak current	< 500ns / duty cycle <5%	lop			750	mA	
Rise and fall time			1		2	nsec	
Threshold current		I _{th}		90	120	mA	
Forward voltage	at I _{op}	V _{op}		1.95	2.05	V	
Peak wavelength λ _{peak} (3)	at Pop, without FBG	λ	781	786	791	nm	
Spectral width (FWHM) (3)	at P _{op} , without FBG	Δλ	0.05	multiple peaks, 0.1	<1	nm	
Spectral width (FWHM) (4)	at Pop , with FBG only	Δλ	0.05	0.08	0.5	nm	
Optical power stability	at I _{op} , t = 60 sec	P _{op} / t			0.5	%	
Polarization extinction ratio (2)	PM fiber version		6	14		dB	
Spectral shift with temp.	FBG Temp.	Δ/T			0.012	nm/ °C	
Spectral shift with current no FBG	(c.w.)			5		nm/A	
Spectral shift with current no FBG	(100ns / duty cycle 1%)			1		nm/A	
Side mode suppression (3)	at Pop, with FBG			20		dB	
Monitor responsivity		R	1	5	20	μA / mW	
Monitor dark current				5	40	nA	
TEC current	chip 25°C, case 70°C	I _{TEC}		1.1		Α	
TEC voltage	chip 25°C, case 70°C	V_{TEC}		1.9		V	
Thermistor resistance	T=25°C	R _{th}	9.5	10	10.5	kOhm	
Thermistor B constant		В	3850	3950	4050	K	
Steinhart-Hart-Equation coefficients C ₁ = 1.1292E-03 / C ₂ = 2.3411E-04 / C ₃ = 8.7755E-08							
Large signal modulation bandwidth				200		MHz	

Fiber Specifications

Fiber type

single mode HI780 fiber (PM780 on request)

Note

1) Ensure sufficient protection against high energy back reflection pulses from solid state lasers. High energy back reflection damages the diode (for example stimulated Brillouin scattering). Typical damage threshold for 8ns puls @200KHz is 0.05µJ (this level is not covered under warranty).
2) Intensity noise of light from modules with PM fiber after polarizer increases with lower polarization extinction ratio (example 6 /10/13 dB can result in intensity noise as high as 50/20/5 %). The intensity noise is sensitive to varying stress (by mechanical and temperature effects) introduced to the PM fiber.
3) Wavelength is measured in air. Without wavelength stabilisation by a fiber bragg grating (FBG) multiple peaks (side modes) around the average wavelength for a specific current in a range of (1-3) nm are observed. The full width half maximum (FWHM) of those peaks can suddenly narrow or broaden. Side mode suppression counts the first side peaks to the main peak. A peak is defined by significant lower values left and right to this peak.
4) With wavelength stabilisation by a fiber bragg grating (FBG) a single peak with accuracy of +-1nm of the center wavelength for a specific current is observed. The full width half maximum (FWHM) of this single peak is stable over time as long as it it is not disturbed by further back reflection from the outgoing optical

5) Rise and fall depends on appropriate driver and can be lower than 1ns with the low inductive version.

Absolute Maximum Ratings

Storage temp.	T _{max}	-40	85	°C
Operating case temp.	T _{op, case}	-20	70	°C
Operating chip temp.	T _{op, chip}	20	40	°C
Soldering temp. (max. 10sec)		260		°C
LD forward current (c.w.)	I _{op max}		600	mA
LD forward current (Pulse 500ns	700	mA		
LD reverse voltage	V _{R, max}		2	V
Monitor forward current	I _{F, PD}		5	mA
Monitor reverse voltage	V _{R, PD}		20	V
TEC current	I _{TEC}		2.5	Α
TEC voltage	V _{TEC}		3.2	V
ESD damage (1)			500	V
Fiber pigtail bend radius	25	mm		
Maximum transient (<3µs) forward	0.7	Α		

(1) A standard human body model (1.5kOhm, 1000pF) is used for ESD thresholds

Note

Absolute maximum rating for the laser diode operating current in cw mode may be applied for short period of time only (<10s). Exposure to maximum ratings for extended period of time or exposure above one or more max ratings may cause damage or affect the reliability of the device.

User Safety







We manufacture diode lasers.